TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (MACH II π -MOS V)

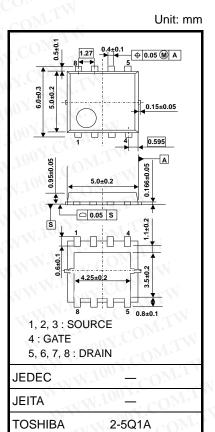
TPCA8010-H

High-Speed Switching Applications Switching Regulator Applications DC-DC Converter Applications

- · Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: QSW = 3.7 nC (typ.)
- Low drain-source ON-resistance: RDS (ON) = 0.38Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 3.9S$ (typ.)
- Low leakage current: $I_{DSS} = 100 \mu A \text{ (max) (V}_{DS} = 200 \text{V)}$
- Enhancement mode: $V_{th} = 2.0 \text{ to } 4.0 \text{ V (VDS} = 10 \text{ V, ID} = 1 \text{ mA)}$

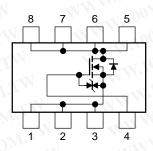
Absolute Maximum Ratings (Ta = 25°C)

Chara	cteristic	Symbol	Rating	Unit
Drain-source volta	ge	V_{DSS}	200	V
Drain-gate voltage	$(R_{GS} = 20 \text{ k}\Omega)$	V _{DGR}	200	V
Gate-source voltage	је	V _{GSS}	±20	V
Drain current	DC (Note 1)	lD	5.5	OM
Drain current	Pulsed (Note 1)	I _{DP}	.11	A
Drain power dissip	ation (Tc=25°C)	P _D	45	W
Drain power dissip	ation (t = 10 s) (Note 2a)	P _D	2.8	w
Drain power dissip	ation (t = 10 s) (Note 2b)	rvi _{PD}	1.6	w
Single-pulse avala	nche energy (Note 3)	E _{AS}	19	mJ
Avalanche current	1007.00	I _{AR}	5.5	A
Repetitive avalance	he energy (Tc=25°C) (Note 4)	E _{AR}	1.5	mJ
Channel temperate	ıre	CO T _{ch}	150	°C
Storage temperatu	re range	T _{stg}	-55 to 150	°C



Weight: 0.069 g (typ.)

Circuit Configuration



Note: For Notes 1 to 4, refer to the next page.

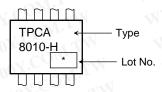
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

Thermal Characteristics

nermal Characteristics			
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc=25°C)	R _{th (ch-c)}	2.78	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	44.6	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th} (ch-a)	78.1	°C/W

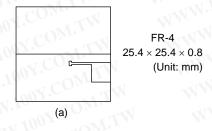
Marking (Note 5)

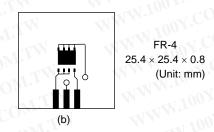


Note 1: The channel temperature should not exceed 150°C during use.

Note 2: (a) Device mounted on a glass-epoxy board (a)

(b) Device mounted on a glass-epoxy board (b)





Note 3: $V_{DD} = 50 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 1mH, $R_G = 25 \Omega$, $I_{AR} = 5.5 \text{ A}$

Note 4: Repetitive rating: pulse width limited by max channel temperature

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Note 5: * Weekly code: (Three digits)

Week of manufacture (01 for first week of year, continuing up to 52 or 53) Year of manufacture (The last digit of the calendar year)

Electrical Characteristics (Ta = 25°C)

Ch	naracteristic	Symbol	Test Condition	Min	Тур.	Max	U
Gate leakage cui	rrent	I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	N er n	_	±10	μ
Drain cutoff curre	ent	IDSS	V _{DS} = 200 V, V _{GS} = 0 V		_	100	μ
WILL	W. 100x	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	200		_	
Drain-source bre	akdown voltage	V(pp) pov	$I_D = 10 \text{ mA}, V_{GS} = -5 \text{ V}$	200	- N	_	V
MTW	WW.10	V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	150		_	
Gate threshold v	oltage	V _{th}	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$	2.0	II	4.0	V
Drain-source ON	-resistance	R _{DS} (ON)	$V_{GS} = 10 \text{ V}, I_D = 2.7 \text{ A}$		0.38	0.45	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, I_{D} = 2.7 \text{ A}$	1.8	3.9	_	S
Input capacitance		C _{iss}	TW WWW.	N-C	600	N —	
Reverse transfer	capacitance	C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	OX.C	20	1	pl
Output capacitar	ice	Coss	OM.	- 	220	W	pF
100X.COM	Rise time	W.100 kr	$V_{GS} \stackrel{10}{\circ} V \qquad I_{D} = 2.7 \text{ A}$	100	8	V.I.N	
N.100Y.CO	Turn-ON time	ton	ON TO VOUT	W.±00	17		
Switching time	Fall time	tf	VDD ≈ 100 V		13	$0\overline{M}$	ns
MM.1007.	Turn-OFF time	t _{off}	Duty ≤ 1%, t _W = 10 μs	AN AN	70	.c o M	T
Total gate charge (gate-source plus		Qg	100X'COM'.	NW	10	V.CO	M.
Gate-source cha	rge	Q _{gs}	$V_{DD} \approx 160 \text{ V}, V_{GS} = 10 \text{ V},$	VI VI	7.6	07.	
Gate-drain ("mille	er") charge	Q _{gd}	I _D = 5.5 A	W	2.4	007.0	nC
Gate switch char	ge	Q _{sw}	W.100Y.COM.TW	_	3.7	700_{X}	C

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Source-Drain Ratings and Characteristics (Ta = 25°C)

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	Unit	Max	Тур.	Min	Test Condition	Symbol	stic	Characteris
Drain reverse current Pulse (Note 1) I _{DRP} — — — 11	A	11	-1	N_	MAMMINTONICOM	I _{DRP}	Pulse (Note 1)	Orain reverse current
Forward voltage (diode) V_{DSF} $I_{DR} = 5.5 \text{ A}, V_{GS} = 0 \text{ V}$ $ -2.0$	V	-20		XX	Inn = 5.5 A Voc = 0.V	V5.05	·10 /	Converd voltage (diede)

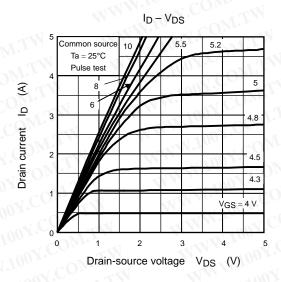
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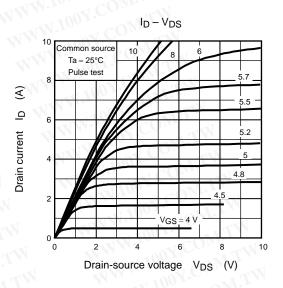
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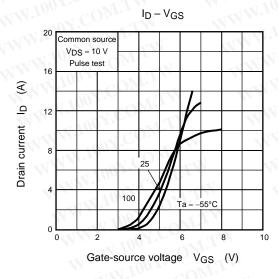
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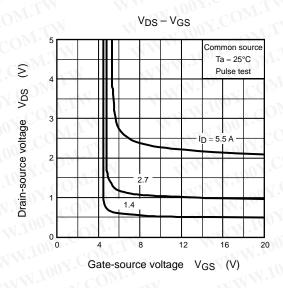
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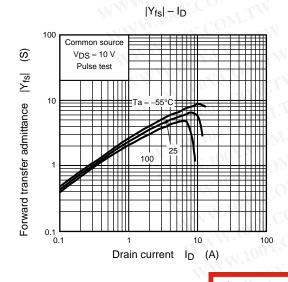
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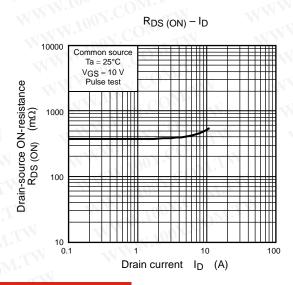


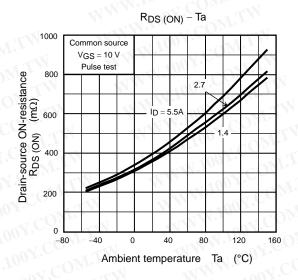


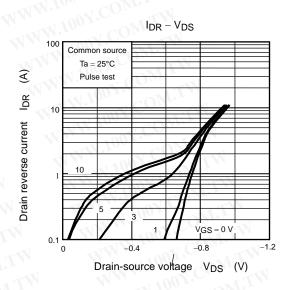


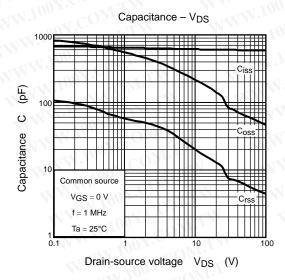


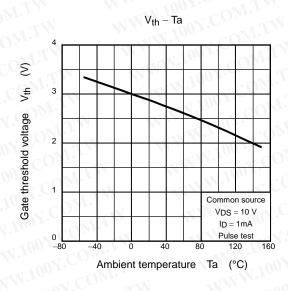


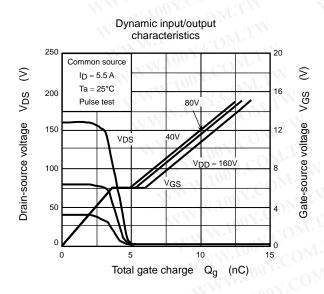


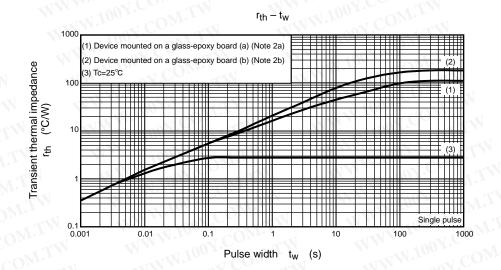


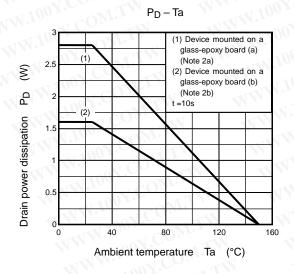


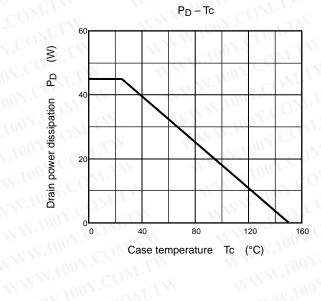


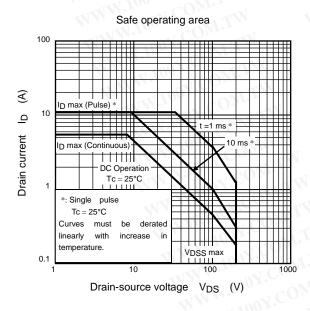












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